



P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

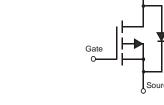
Features

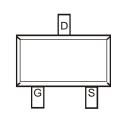
- P-Channel MOSFET
- Low On-Resistance
 - 150 mΩ @ V_{GS} = -4.5V
 - 200 m Ω @ V_{GS} = -2.5V
 - 240 m Ω @ V_{GS} = -1.8V
- Very Low Gate Threshold Voltage V_{GS(th)} ≤ 1V
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.006 grams (approximate)







Top View

Top View

Maximum Ratings @TA = 25°C unless otherwise specified

Internal Schematic

Drain

| Characteristic | | Symbol | Value | Units |
|------------------------|--------------------------------|------------------|--------------|-------|
| Drain-Source Voltage | | V_{DSS} | -20 | V |
| Gate-Source Voltage | | V _{GSS} | ±12 | V |
| Drain Current (Note 1) | $T_A = 25$ °C $T_A = 70$ °C | I _D | -1.5 -1.0 | А |
| Pulsed Drain Current | | I _{DM} | -5 | Α |

Thermal Characteristics

| Characteristic | Symbol | Value | Units |
|---|-------------------|-------------|-------|
| Total Power Dissipation (Note 1) | P_{D} | 250 | mW |
| Thermal Resistance, Junction to Ambient | $R_{	hetaJA}$ | 500 | °C/W |
| Operating and Storage Temperature Range | $T_{J_i} T_{STG}$ | -55 to +150 | °C |

Notes: 1. Device mounted on FR-4 substrate PC board, 2oz. Copper, with minimum recommended pad layout.

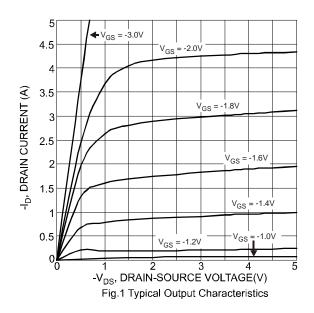
- 2. No purposefully added lead.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

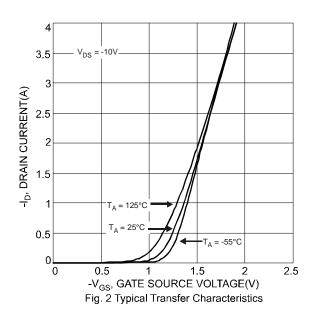


Electrical Characteristics @TA = 25°C unless otherwise specified

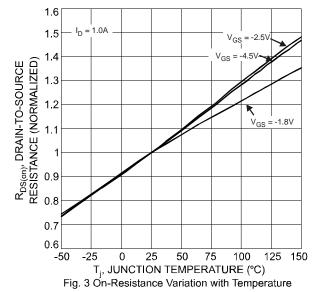
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|-----------------------------------|---------------------------------|----------------------|-------|-----|--------------|---|--|
| OFF CHARACTERISTICS (Note 4) | | | | | | | |
| Drain-Source Breakdown Voltage | | BV _{DSS} | -20 | _ | _ | V | $V_{GS} = 0V, I_D = -250\mu A$ |
| Zero Gate Voltage Drain Current | $T_J = 25$ °C $T_J = 125$ °C | I _{DSS} | _ | | -1.0 -5.0 | μΑ | V _{DS} = -20V, V _{GS} = 0V |
| Gate-Source Leakage | | I _{GSS} | _ | _ | ±100 | nA | $V_{GS} = \pm 12V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 4) | | | | | | | |
| Gate Threshold Voltage | | $V_{GS(th)}$ | -0.45 | _ | -1.0 | V | $V_{DS} = V_{GS}$, $I_D = -250\mu A$ |
| | | | | 92 | 150 | | $V_{GS} = -4.5V$, $I_D = -2.0A$ |
| Static Drain-Source On-Resistance | | R _{DS (ON)} | _ | 134 | 200 240 | mΩ | $V_{GS} = -2.5V, I_D = -1.5A$ |
| | | | | 180 | | | $V_{GS} = -1.8V, I_D = -0.5A$ |
| Forward Transconductance | | g fs | _ | 3.1 | _ | S | $V_{DS} = -10V, I_{D} = -810mA$ |
| Diode Forward Voltage (Note 4) | | V _{SD} | _ | _ | -0.9 | V | $V_{GS} = 0V, I_{S} = -0.5A$ |
| DYNAMIC CHARACTERISTICS | | | | | | | |
| Input Capacitance | | C _{iss} | | 320 | _ | pF | 101/11/101/ |
| Output Capacitance | Coss | _ | 80 | _ | pF | $V_{DS} = -16V, V_{GS} = 0V$ -f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{rss} | _ | 60 | _ | pF | 1 = 1.01/1112 | |
| Turn-On Delay Time | t _{D(on)} | _ | 12.5 | _ | ns | | |
| Turn-On Rise Time | t _r | — | 10.3 | _ | ns | $V_{DS} = -10V, V_{GS} = -4.5V,$ | |
| Turn-Off Delay Time | t _{D(off)} | _ | 46.5 | | ns | $R_L = 10\Omega$, $R_G = 1.0\Omega$ | |
| Turn-Off Fall Time | t _f | _ | 22.2 | _ | ns | | |

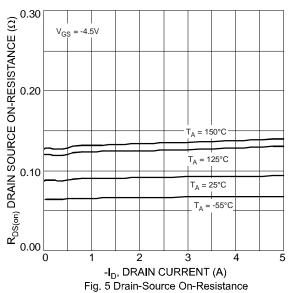
Notes: 4. Short duration pulse test used to minimize self-heating effect.

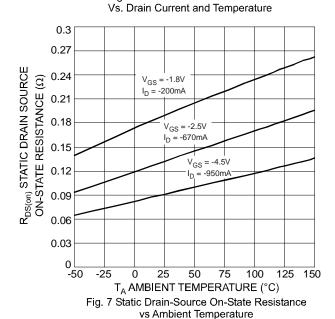












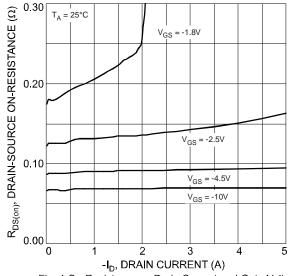
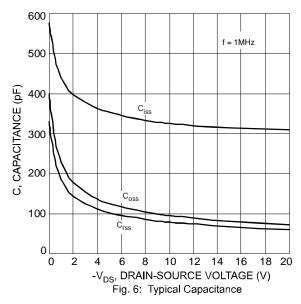
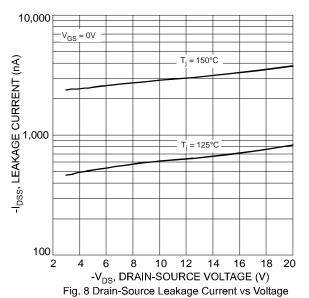
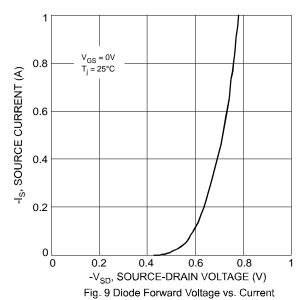


Fig. 4 On-Resistance vs Drain Current and Gate Voltage







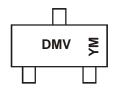


Ordering Information (Note 5)

| Part Number | Case | Packaging |
|-------------|---------|------------------|
| DMP2240UW-7 | SOT-323 | 3000/Tape & Reel |

5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:

Marking Information



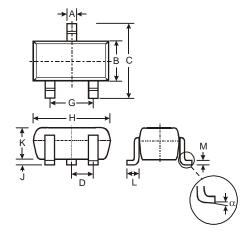
DMV = Product Type Marking Code YM = Date Code Marking Y = Year (ex: V = 2008)

M = Month (ex: 9 = September)

Date Code Key

| Year | 2008 | | 2009 | 2010 | | 2011 | 2012 | | 2013 | 2014 | | 2015 |
|-------|------|-----|------|------|-----|------|------|-----|-------|------|-----|------|
| Code | V | | W | Х | | Υ | Z | | Α | В | | С |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | g Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |

Package Outline Dimensions



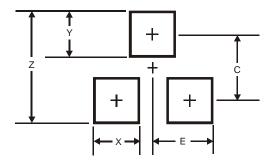
| SOT-323 | | | | | | |
|---------|----------------------|------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.25 | 0.40 | 0.30 | | | |
| В | 1.15 | 1.35 | 1.30 | | | |
| С | 2.00 | 2.20 | 2.10 | | | |
| D | - | 0. | | | | |
| G | 1.20 | 1.40 | 1.30 | | | |
| Н | 1.80 | 2.20 | 2.15 | | | |
| J | 0.0 | 0.10 | 0.05 | | | |
| K | 0.90 | 1.00 | 1.00 | | | |
| L | 0.25 | 0.40 | 0.30 | | | |
| М | 0.10 | 0.18 | 0.11 | | | |
| α | 0° | 8° | - | | | |
| All | All Dimensions in mm | | | | | |

May 2010

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Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.8 |
| Х | 0.7 |
| Υ | 0.9 |
| С | 1.9 |
| E | 1.0 |

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